

Product Features

- 2.6-3.8GHz GaN MMIC Power Amplifier
- Typical Small-signal Gain 27.1dB
- Typical Power Gain 22.7dB
- Typical Output Power 54.7dBm
- Typical PAE 48.9%
- 48V-50V operation

* Above Typical values measured at 3.2GHz and 48V

Applications

- General Purpose
- Communication System
- Radar System
- Satellite Communication



Absolute Maximum Rating

Parameter	Symbol	Rating	Units	Conditions
Drain-Source Voltage	V _{DSS}	120	Volts	25°C
Gate-to-Source Voltage ³	V _{GS}	-10, +2	Volts	25°C
Storage Temperature ³	T _{STG}	-65, +150	°C	
Operating Junction Temperature ^{1,3}	T _J	225	°C	
Maximum Forward Gate Current ³	I _{GMAX}	10	mA	25°C
Maximum Drain Current ²	I _{DMAX}	1.04	A	I _d @ V _d =10V, V _g = 1V
Soldering Temperature ³	T _s	245	°C	

1. Continuous use at maximum temperature will affect MTTF.

2. Current limit for long term, reliable operation.

3. After additional updates.

Specifications (T_c=25°C, F₀=3.2GHz, V_{DD}=48V, I_{DQ}=454mA)

Parameter	Symbol	MIN	TYP	MAX	Units	Conditions
Small Signal Gain	G		27.1		dB	Pulse Width=100μsec, Duty Cycle=10%
Power Gain	G _P		22.7		dB	Psat @ I _{gs} =1mA
Saturated Output Power	P _{OUT}		54.7		dBm	Psat @ I _{gs} =1mA
Power Added Efficiency	PAE		48.9		%	Psat @ I _{gs} =1mA

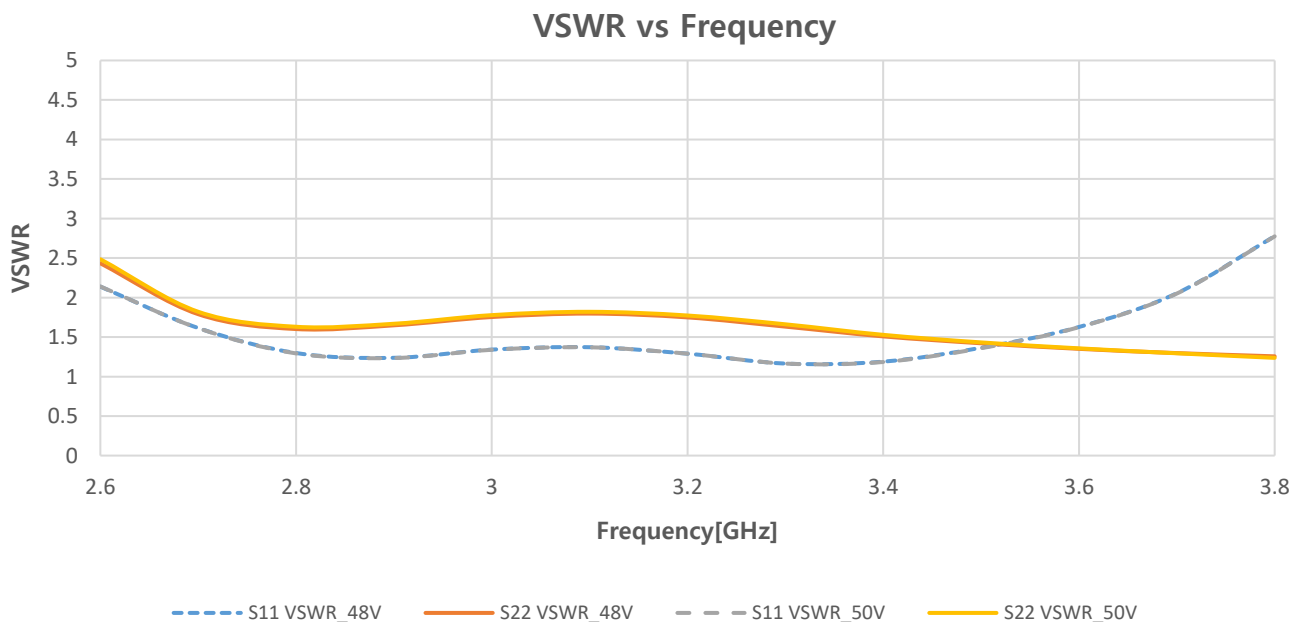
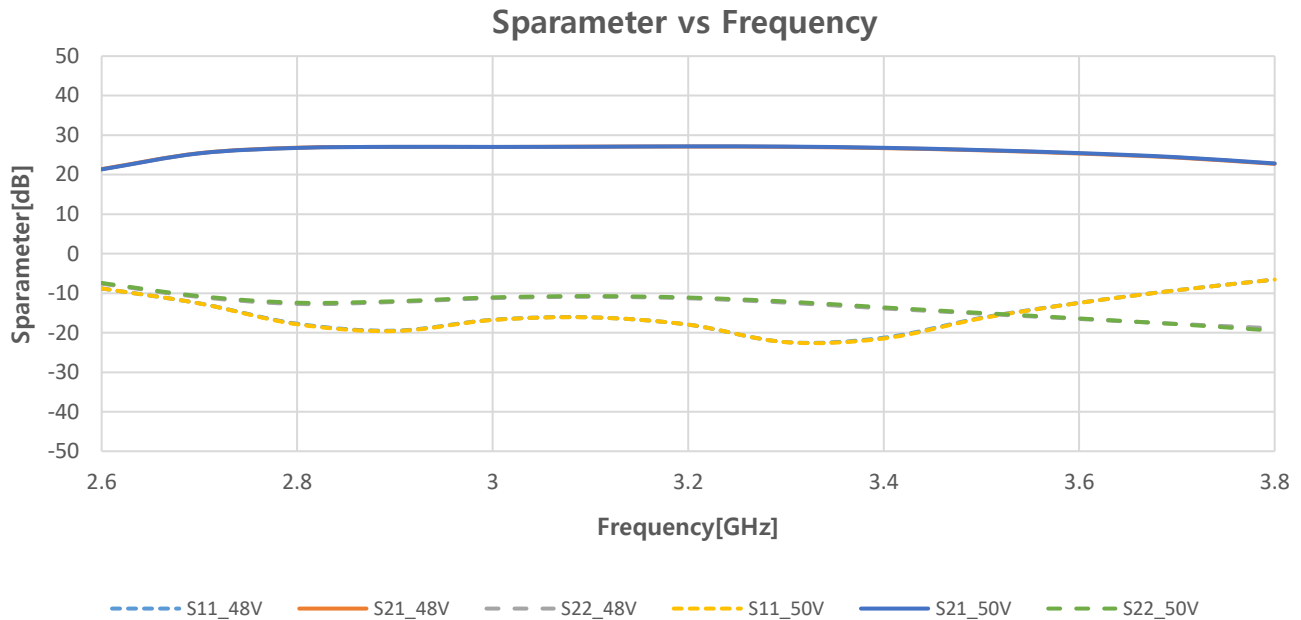
Specifications (T_c=25°C, F₀=3.2GHz, V_{DD}=50V, I_{DQ}=476mA)

Parameter	Symbol	MIN	TYP	MAX	Units	Conditions
Small Signal Gain	G		27.2		dB	Pulse Width=100μsec, Duty Cycle=10%
Power Gain	G _P		23		dB	Psat @ I _{gs} =1mA
Saturated Output Power	P _{OUT}		55		dBm	Psat @ I _{gs} =1mA
Power Added Efficiency	PAE		48.1		%	Psat @ I _{gs} =1mA



Small-Signal Performance (Tc=25°C)

Drain Voltage= (48V IDQ=454mA), (50V IDQ=476mA)

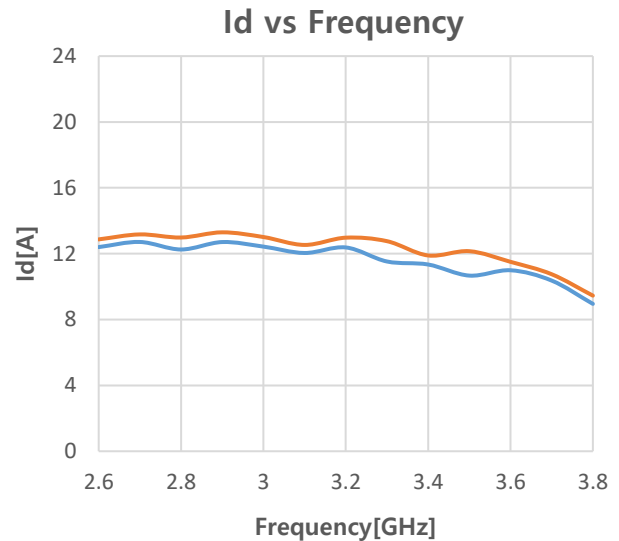
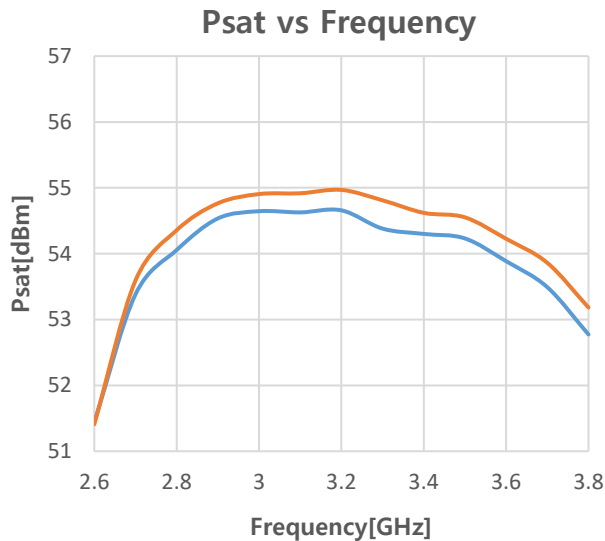




Psat, Id vs Frequency Performance (Tc=25°C)

Drain Voltage= (48V IDQ=454mA), (50V IDQ=476mA)

Pulse-Mode(Pulse Width=100μsec, Duty Cycle=10%)



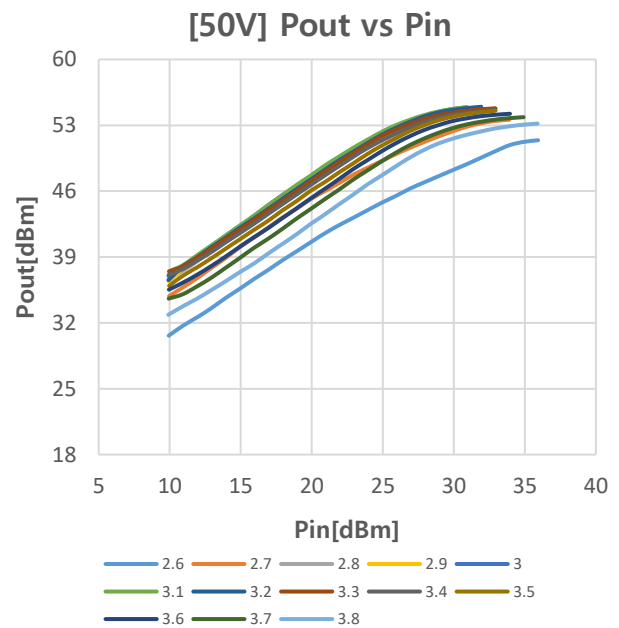
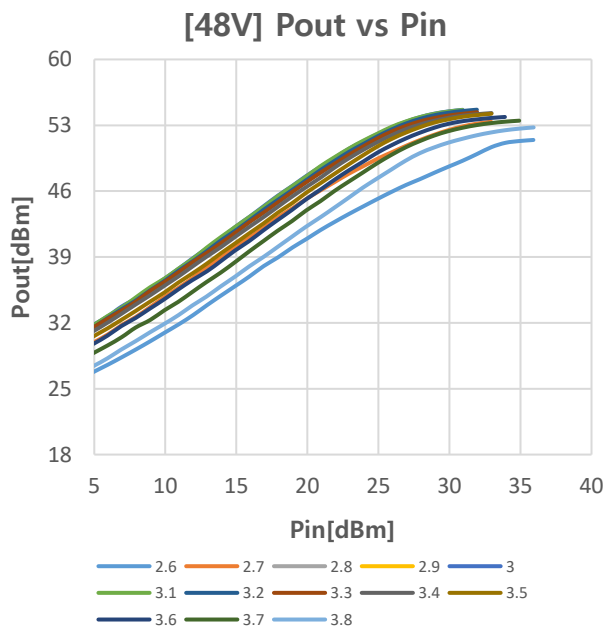
— PULSE_48V — Pulse_50V

— PULSE_48V — Pulse_50V

Output Power (Pout) vs Input Power (Pin) Performance (Tc=25°C)

Drain Voltage= (48V IDQ=454mA), (50V IDQ=476mA)

Pulse-Mode(Pulse Width=100μsec, Duty Cycle=10%)

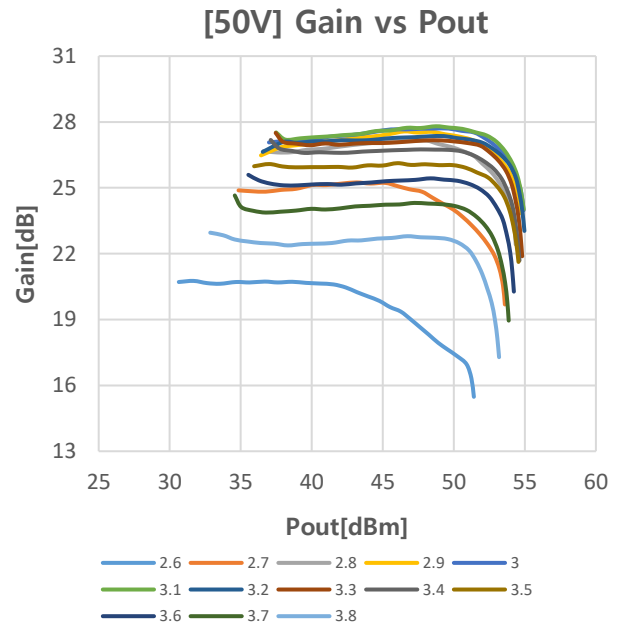
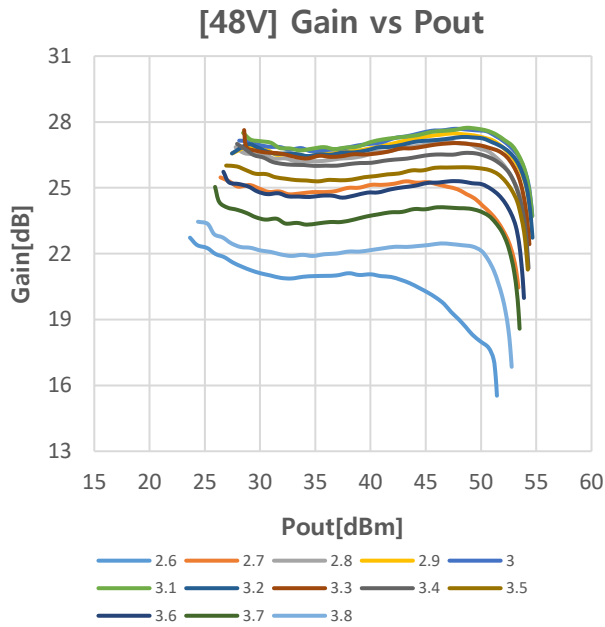




Gain vs Output Power (Pout) Performance (Tc=25°C)

Drain Voltage= (48V IDQ=454mA), (50V IDQ=476mA)

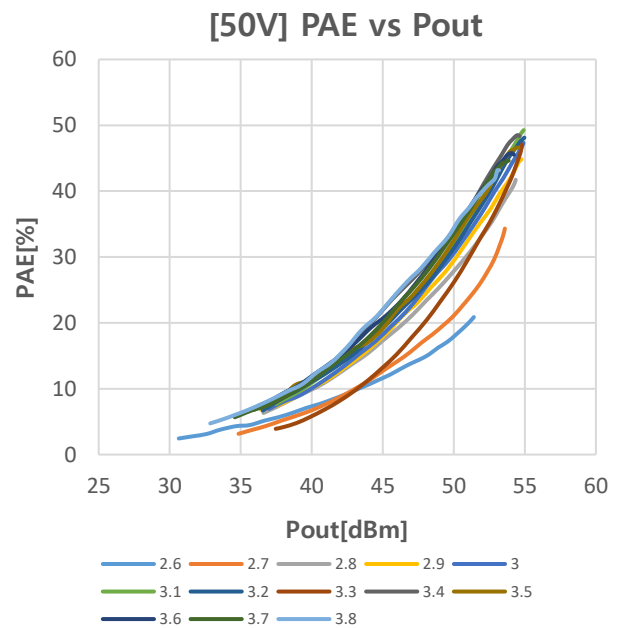
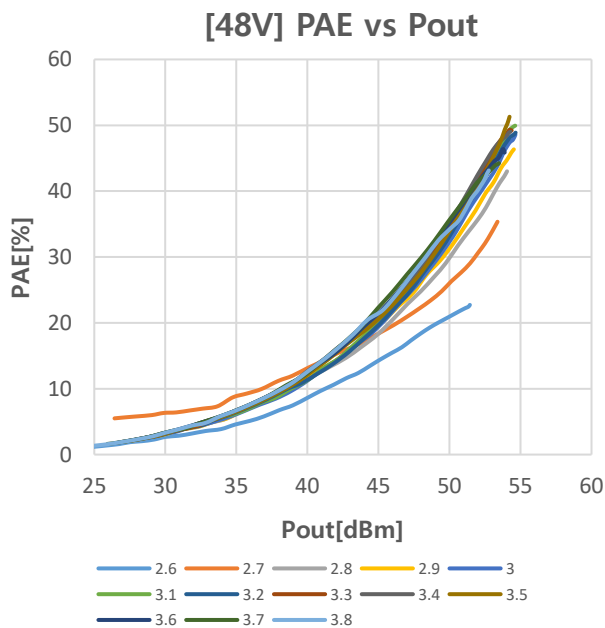
Pulse-Mode(Pulse Width=100μsec, Duty Cycle=10%)



PAE vs Output Power (Pout) Performance (Tc=25°C)

Drain Voltage= (48V IDQ=454mA), (50V IDQ=476mA)

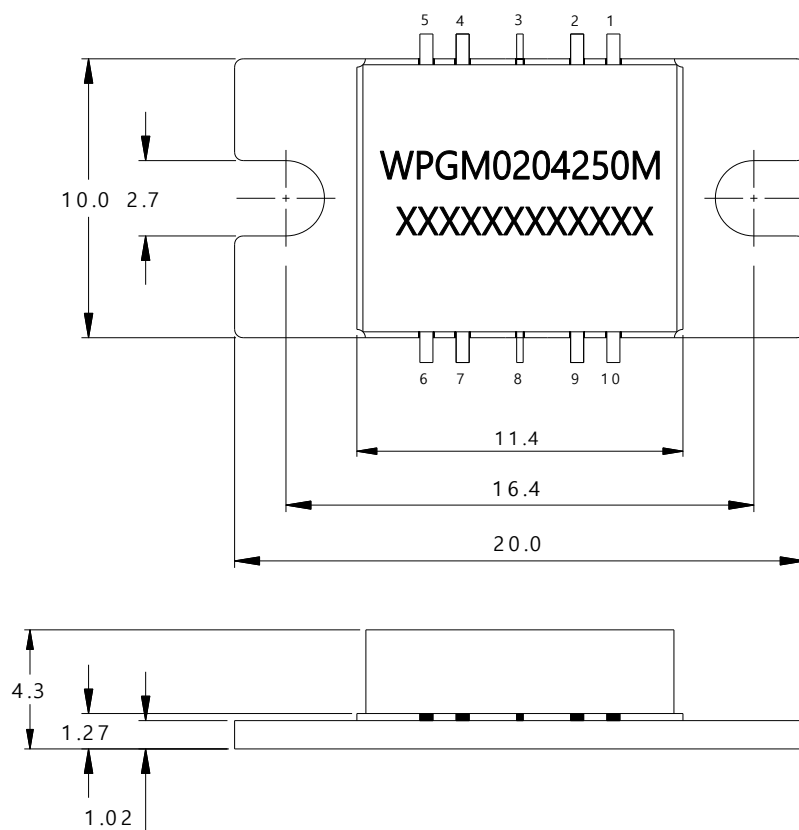
Pulse-Mode(Pulse Width=100μsec, Duty Cycle=10%)





Product Dimension

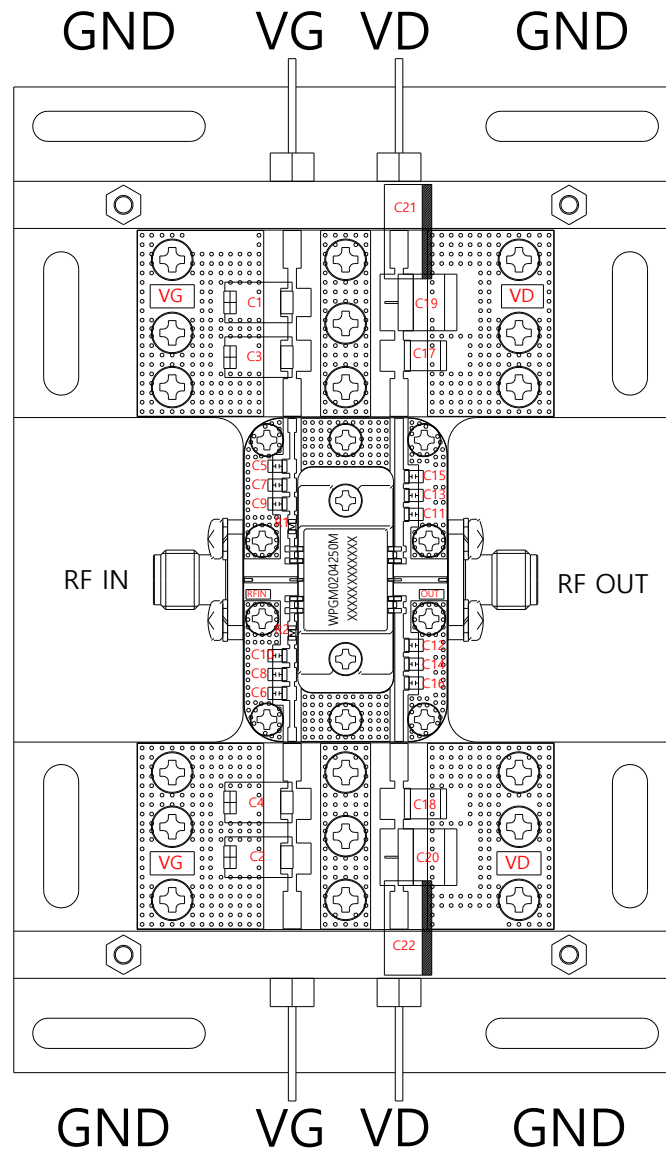
- Product Type: MPKG, 10-lead bolt-down
- Unit: mm



Pin No.	Function	Description
1, 5	VG	Gate Bias, bias must be applied to both pins
2, 4	No Connect	Pin can be open circuit
3	RF IN	50 ohm RF input, included DC Blocking Capacitors
6, 10	VD	Drain, Bias, bias must be applied to both pins
7, 9	No Connect	Pin can be open circuit
8	RF OUT	50 ohm RF output, included DC Blocking Capacitors
Flange	Ground	RF and DC Ground



Evaluation Board Circuit Outline





Bias Sequence

1. VG connection must be biased from both sides.
2. VD connection must be biased from both sides.
3. VG bias must be applied before VD

Test Condition

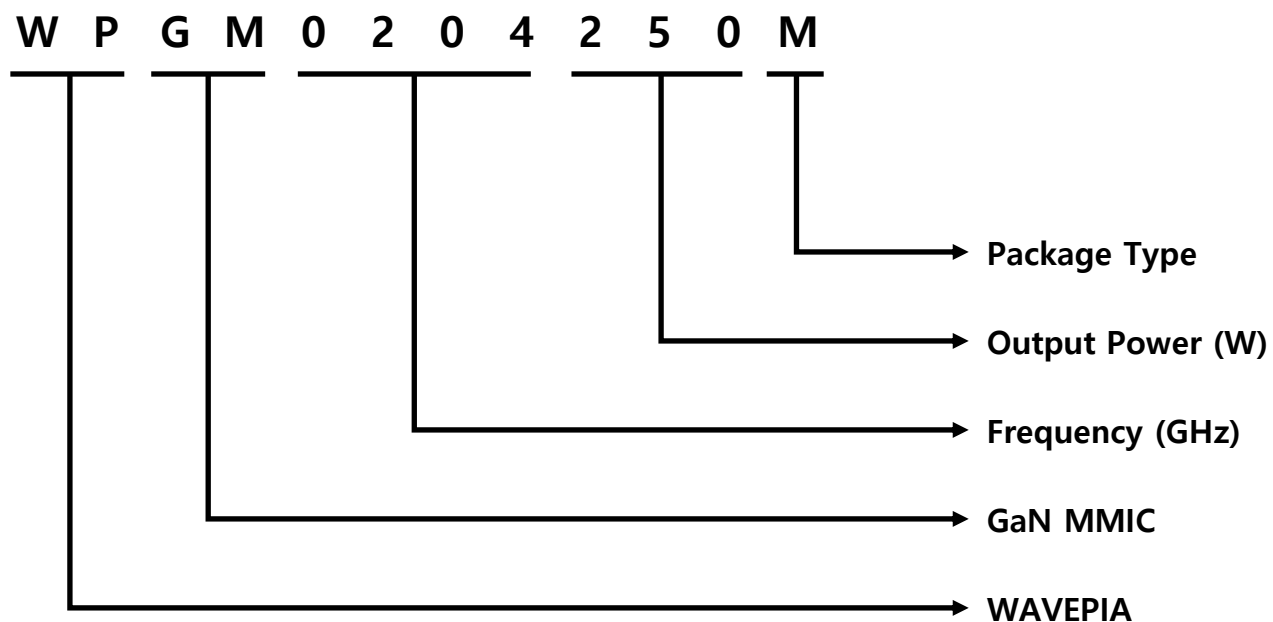
1. VD=48V, IDQ=454mA, VG=-2.77V
2. VD=50V, IDQ=476mA, VG=-2.76V

Evaluation Board Circuit Bill of Materials

Reference	Part Number	Value	Description	Package	Manufacturer	EA
C1, C2	293D476X9016D2TE3	47uF / 16V	Tantalium Capacitor	2917	MICRO TECHNOLOGY	2
C3, C4	TAJD106K035RNJ	10uF / 35V	Tantalium Capacitor	2917	KYOCERA AVX	2
C17, C18	CGA8N3X7R2E474K230KA	470nF / 250V	Ceramic Capacitor	1812	TDK	2
C19, C20	22201C106KAT2A	10uF / 100V	Ceramic Capacitor	2020	KYOCERA AVX	2
C5, C6, C15, C16	C2012X7S2A474K125AB	470nF / 100V	Ceramic Capacitor	0805	TDK	4
C7, C8, C13, C14	CL21B103KCANNNC	10nF / 100V	Ceramic Capacitor	0805	SAMSUNG	4
C9, C10, C11, C12	251R15S101JV4E	100pF / 250V	Ceramic Capacitor	0805	JOHANSON	4
R1, R2	WR06X100 JTL	10ohm	Chip Resistor	0603	WALSIN	2
C21, C22	KMG 100V 47uF MAX	E-Cap (Dip Type)	electrolytic capacitor	0603	SAMYOUNG	2
J1, J2	SM06FS064	SMA / 4 Hole	SMA_4 Hole (DC to 26.5 GHz)	-	WITHWAVE	2
P1	-	-	RO4003C 12mil	-	Rogers	1
P2	-	-	RO4003C 12mil	-	Rogers	2
Q1	WPGM0204250M	-	GaN MMIC	-	WAVEPIA	1



Part Number System



Parameter	Value	Units
Lower Frequency	2.6	GHz
Upper Frequency	3.8	GHz
Output Power	250	W
Transistor Type	GaN MMIC	-
Package	MPKG	-



Handling Precautions

Parameter	Classification	Standard
ESD - Human Body Model (HBM)	Class 1A	ANSI/ESDA/JEDEC JS-001-2017
ESD - Charge Device Model (CDM)	Class C2	ANSI/ESDA/JEDEC JS-002-2018
MSL - Moisture Sensitivity Level	N/A	



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Electrostatic
Sensitive Device

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

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